



## Low $V_{CE(SAT)}$ PNP Epitaxial Planar Transistor

# BTA1300A3

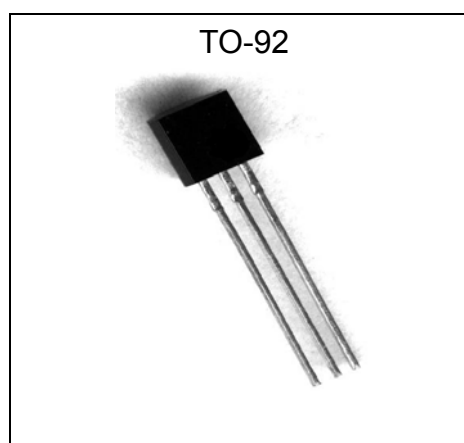
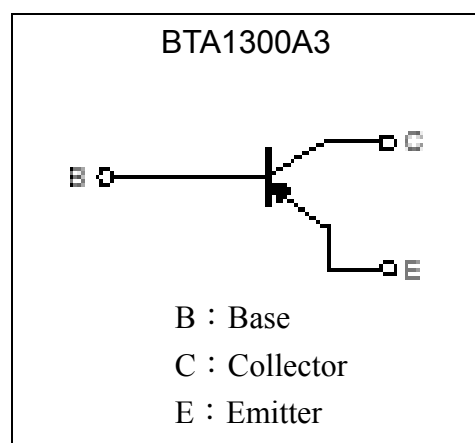
## Description

The BTA1300A3 is designed especially for use in strobo flash and medium power amplifier applications.

## Features

- High DC current gain and excellent hFE linearity.  
HFE(1)=140—600( $V_{CE}=-1V, I_C=-0.5A$ )  
HFE(2)=60(min), 120(typ.)( $V_{CE}=-1V, I_C=-4A$ )
- Low Saturation Voltage  
 $V_{CE(sat)}=-0.5V(max)(I_C=-2A, I_B=-50mA)$ .

## Symbol



## Absolute Maximum Ratings ( $T_a=25^{\circ}C$ )

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	VCBO	-20	V
Collector-Emitter Voltage	VCES	-20	V
Collector-Emitter Voltage	VCEO	-10	V
Emitter-Base Voltage	VEBO	-6	V
Collector Current(DC)	$I_C$	-2	A
Collector Current(Pulsed)(Note 1)	$I_{CP}$	-5	
Power Dissipation	$P_d$	750	mW
Junction Temperature	$T_j$	150	$^{\circ}C$
Storage Temperature	$T_{stg}$	-55~+150	$^{\circ}C$

Note 1: Single pulse,  $P_w \leq 10ms$ , Duty Cycle  $\leq 30\%$ .

**Characteristics** (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BVCBO	-20	-	-	V	IC=-50uA
BVCEO	-10	-	-	V	IC=-10mA
BVEBO	-6	-	-	V	IE=-1mA
ICBO	-	-	-0.1	uA	VCB=-20V
IEBO	-	-	-0.1	uA	VEB=-6V
*VCE(sat)	-	-	-0.5	V	IC=-2A, IB=-50mA
*VBE(on)	-	-	-1.5	V	VCE=-1V, IC=-2A
*hFE 1	140	-	600	-	VCE=-1V, IC=-500mA
*hFE 2	60	120	-	-	VCE=-1V, IC=-4A
fT	-	140	-	MHz	VCE=-1V, IE=500mA, f=100MHz
Cob	-	50	-	pF	VCB=-10V, IE=0A, f=1MHz

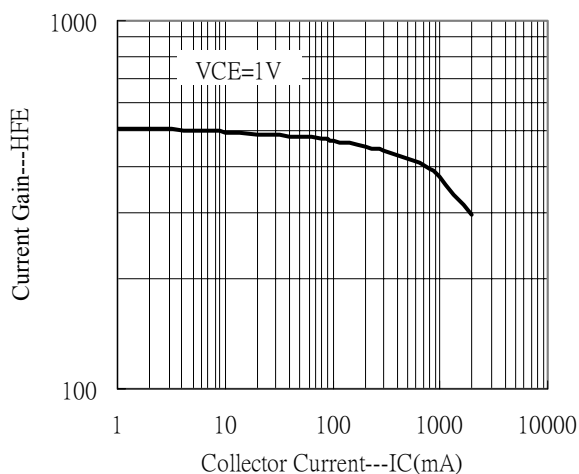
\*Pulse Test: Pulse Width ≤380us, Duty Cycle≤2%

**Classification Of hFE**

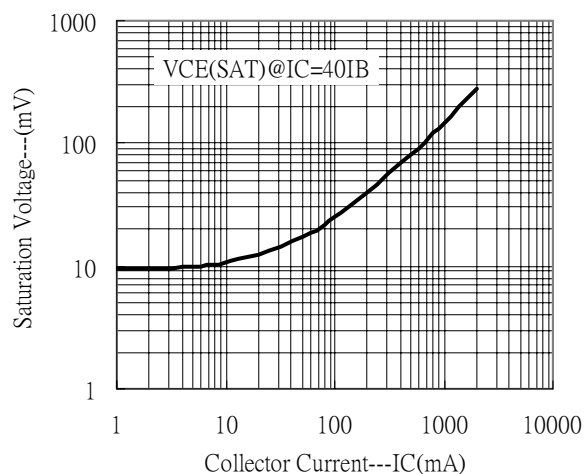
Rank	Y	GR	BL
Range	140~280	200~400	300~600

## Characteristic Curves

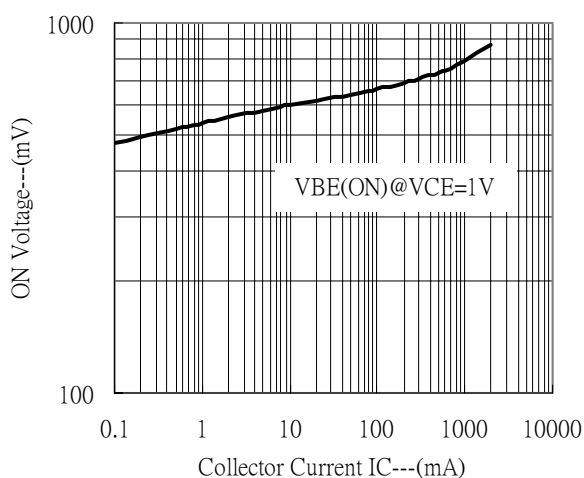
Current Gain vs Collector Current



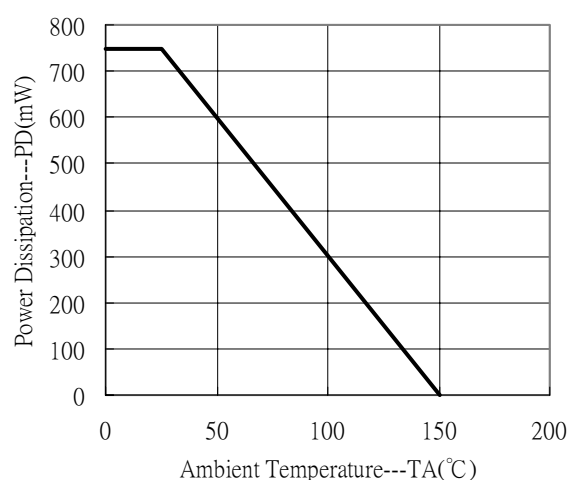
Saturation Voltage vs Collector Current



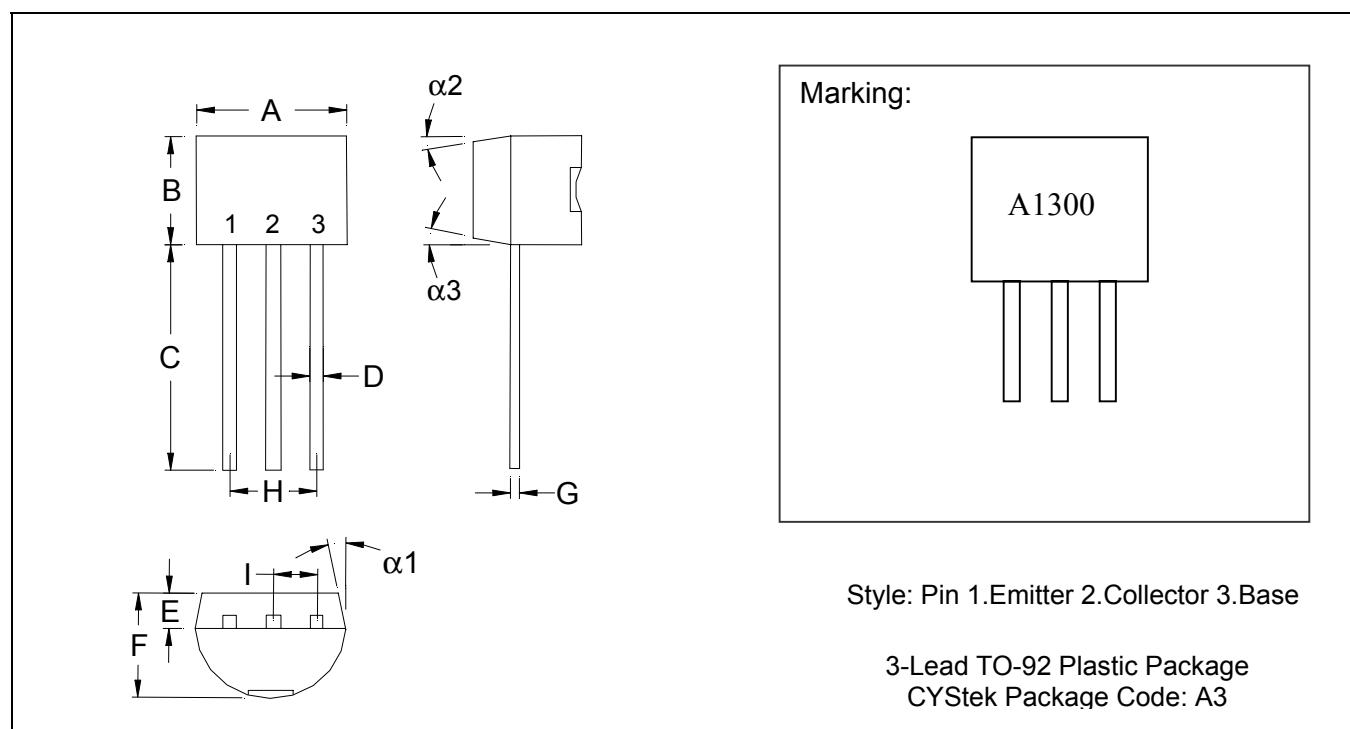
ON Voltage vs Collector Current



Power Derating Curve



## TO-92 Dimension



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1704	0.1902	4.33	4.83	G	0.0142	0.0220	0.36	0.56
B	0.1704	0.1902	4.33	4.83	H	-	*0.1000	-	*2.54
C	0.5000	-	12.70	-	I	-	*0.0500	-	*1.27
D	0.0142	0.0220	0.36	0.56	$\alpha 1$	-	*5°	-	*5°
E	-	*0.0500	-	*1.27	$\alpha 2$	-	*2°	-	*2°
F	0.1323	0.1480	3.36	3.76	$\alpha 3$	-	*2°	-	*2°

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

### Material:

- Lead: 42 Alloy ; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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